## NSN 5961-00-497-1020

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-497-1020 **Inclosure Material:** Glass and metal **Overall Length:** 0.820 inches **Overall Diameter:** 0.294 inches **Function For Which Designed:** Mixer **Mounting Method:** Compression **Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** 200.0 reverse voltage, dc and 20.0 forward voltage, dc **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius ambient air **Precious Material And Location:** Metal parts plated gold **Test Data Document:** 97942-580r679 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Terminal Type And Quantity:** 2 ferrule **Specification Data:** 81349-mil-s-19500/233 government specification Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: A110a0